



IPW  
PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

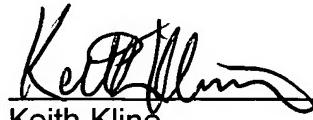
Serial No: 10/615,632 Docket No: 1981036  
Filing Date: 07/08/200 Applicant: Fang, et al.  
Examiner: HITESHEW, FELISA CARLA Art Unit: 1765  
Title: METHOD OF GROWING A SINGEL CRYSTAL GALLIUM  
NITRIDE ON SILICON SUBSTRATE

To: Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**TRANSMITTAL OF AMENDMENT**

1. Transmitted herewith is a response to an office action for this application prepared and submitted by the Applicant.
2. Applicant is entitled to Small Entity Status.
3. The proceedings herein are for a patent application and the provisions of 37 CFR 1.136 apply. Applicant believes that no extension of time is required. However, a conditional petition is hereby made to provide for the possibility that applicant has inadvertently overlooked the need for a petition for extension of time.
4. No fee is required at this time.
5. Certificate of Mailing (37 CFR 1.8a): I hereby certify that this paper (along with any referred to as being attached or enclosed) is being deposited with the United States Postal Service on the date shown below with sufficient postage as First Class Mail in an envelope addressed to: Mail Stop Non-Fee Amendment, Commissioner for Patents, P.O. Box 1450, Arlington, VA 22313-1450.

Respectfully submitted,

  
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**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**



In re the Application of:

Fang, Yean Kuen et al

Confirmation No.: 1450

Serial No.: 10/615,632

Art Unit: 1765

Examiner: HITESH, FELISA CARLA

Filed: 07/08/2003

Docket No.: 1981036

For: METHOD OF GROWING SINGLE CRYSTAL GALLIUM  
NITRIDE ON SILICON SUBSTRATE

**AMENDMENT**

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

May 23, 2005

Dear Sir:

In response to the Office Action dated 03/17/2005 (hereinafter outstanding Action), please reconsider the above-identified application based on the following amendments, which follow a revised amendment format under 37 C.F.R. §1,121.